

***MMIC Integration & Packaging for  
Defence & Automotive Radar:  
Size & Cost Reductions Create  
New Market Opportunities***

**October 9, 2013**

# Outline

- Overview
- Radar: commercial and defence
- Spatium™ power amplifiers
- AESA radar components
- RF packaging
- Summary



# Synergistic Organization

## **Mobile Devices**

Drives volume scale, lower costs  
& speed of innovation

**TriQuint**  
Accelerating the  
Next Generation  
of RF

## **Defense**

Drives technology research  
& product solutions

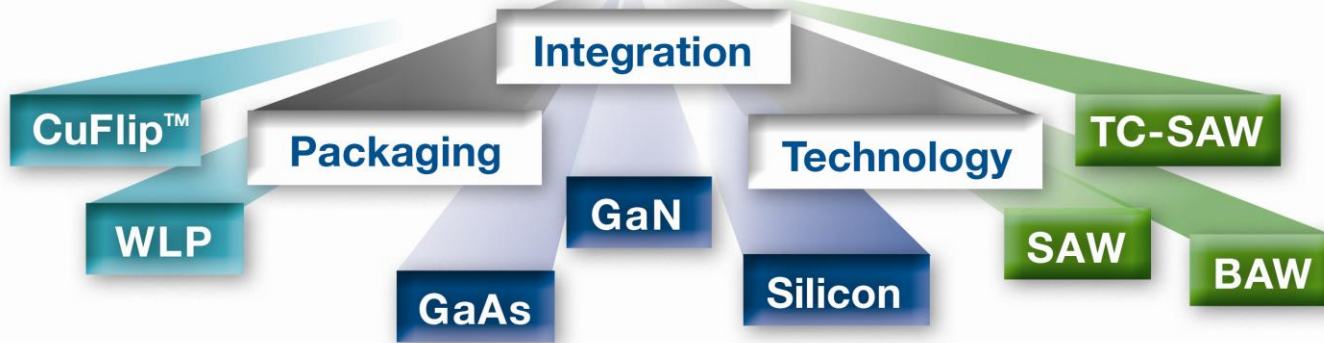
## **Network Infrastructure**

Drives high-performance  
product portfolio

# Technology Integration Leader

- TriQuint is the only high-volume supplier integrating advanced, in-house active and passive technologies for the broad market

## INNOVATION

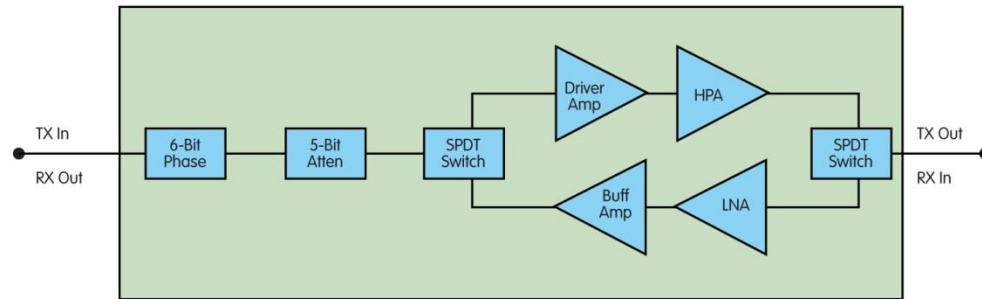


### CUSTOMER BENEFITS

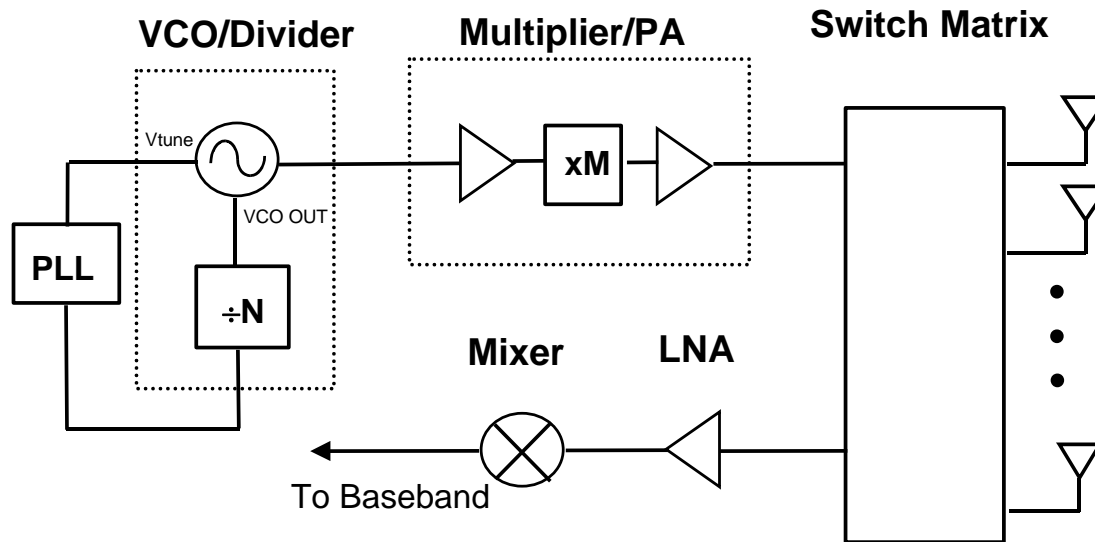
- Minimize board space
- Saves engineering resources
- Maximize power efficiencies
- Reduced BOM
- Streamlined manufacturing



# Basic Defense and Automotive Radar Block Diagrams



**AESA Radar Basic Block Diagram**



## Pulse and Continuous Wave Radar Concepts

Varying complexity, trending towards more antenna ports for better resolution

# Automotive Sensors / Radar

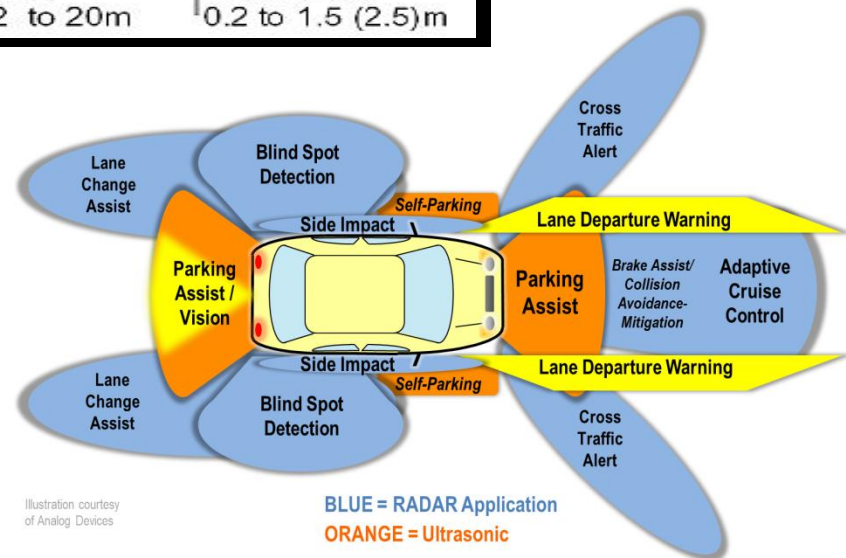
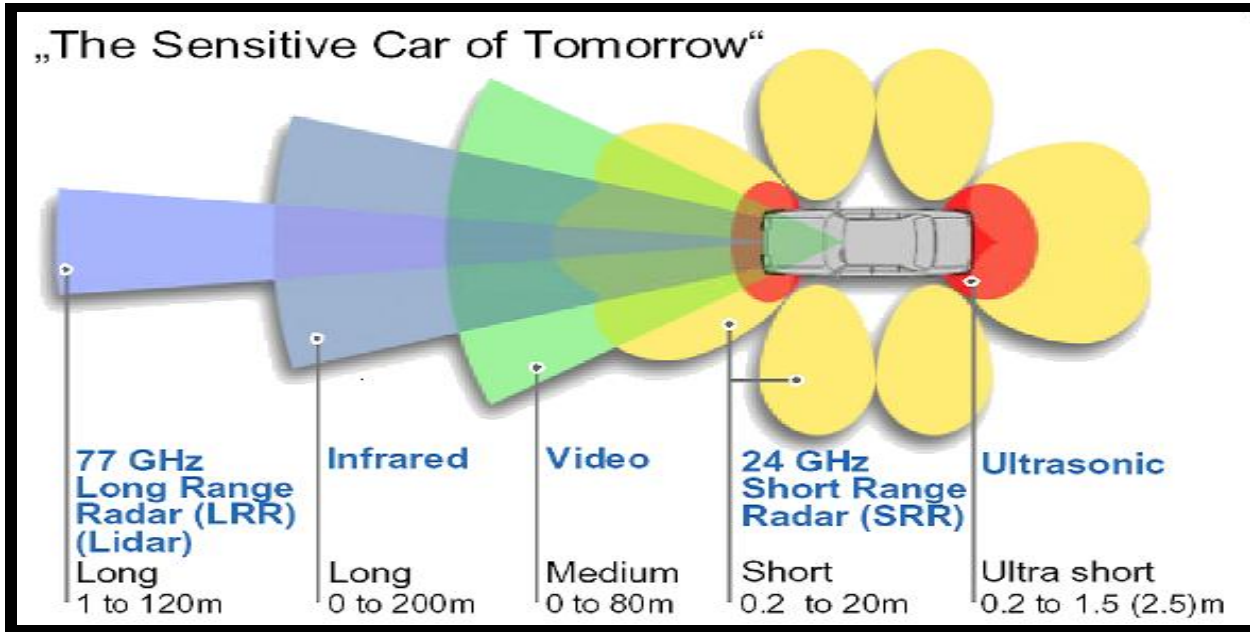


Illustration courtesy of Analog Devices



# *Center Radar: Solid-State Power Amplifier, TWT Replacements*

# Center Feed Radars

## TWTA Based Radar





# TriQuint Spatium™ Power Amplifier Technology

## ▪ Spatium™ power amplifiers

- TWTA upgrade / replacement
- Electronic warfare
- MilCom, data links
- Radar
- Test and measurement

## ▪ Key Spatium™ PA features

- High efficiency
- Compact form-factor
- Low voltage operation
- Graceful degradation
- Short thermal path
- High reliability / long life MTBF
- No aging characteristics
- Frequency scalable



**Solid state PA reliability with PAE equal to or greater than a TWTA**

# ***AESA Radar Components***

# Phased Array Radars

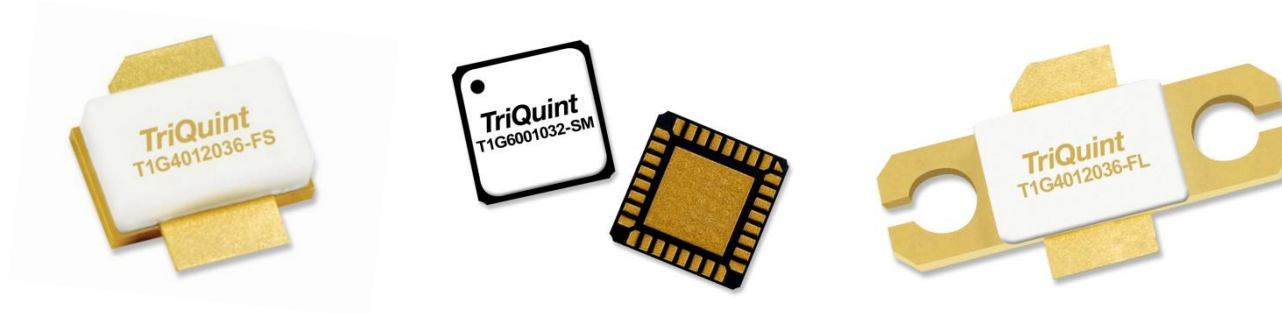
- Radar designers are very focused on size, weight and power (SWaP)



# GaN Packaged Transistors

Part #	Frequency Range (GHz)	Psat (W)	Gain (dB)	DE (%)
T1G6001032-SM*	DC-6	10W	16	53
T1G4012036-FS / -FL	DC-3.5	120W	13	52
T1G4020036-FS / -FL*	DC-3.5	2x120W	13	52
T1G2028536-FS / -FL*	DC-2	250W	18	60
T1G4004532-FS / -FL*	DC-3.5	45W	16	54

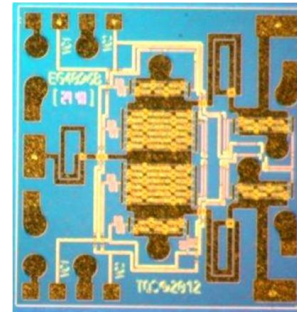
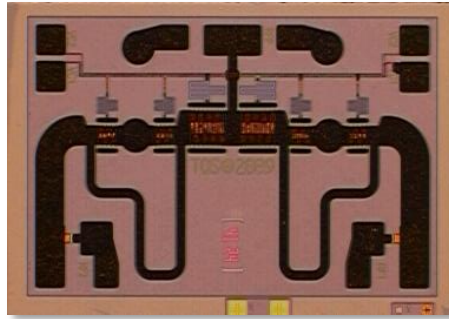
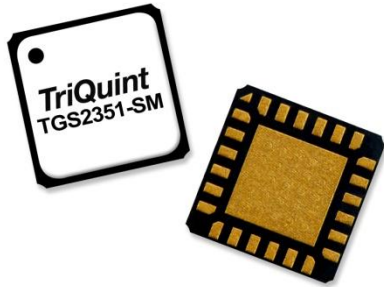
\* In Development





# Transmit / Receive RF Switch

- RF switch loss directly affects NF and PAE



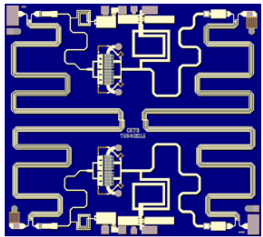
- **High-power switch options**

- Asymmetrical RF switches: high power transmit path, lower loss receive path
- GaN T/R switches
  - High power handling capability (>100W) CW
  - Very low current (<6uA)
  - Low insertion loss (<0.7dB)
  - High RF power handling capability

# GaN Low-Noise Amplifier Products

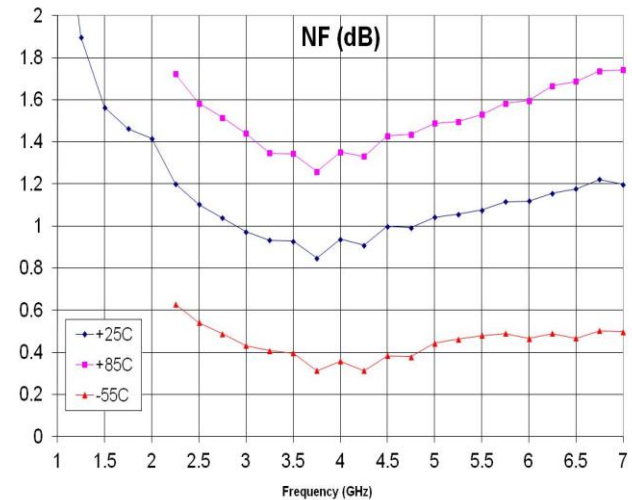
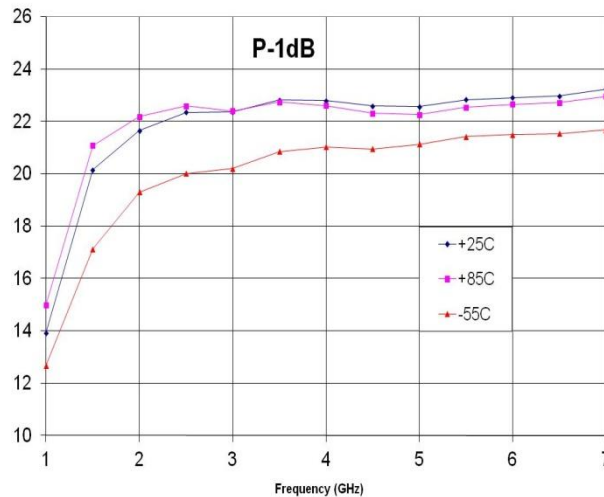
LNA	Frequency (GHz)	P1dB (dBm)	NF (dB)	SS Gain (dB)	TOI (dBm)	Tech	Export
TGA2611*	2-6	22	1	25	30	GaN25	EAR99
TGA2612*	6-12	20	1.5	25	29	GaN25	EAR99

\* Plastic overmold package planned for Q4 2013



3.3x3.0mm

\* 5x5 QFN Planned \*



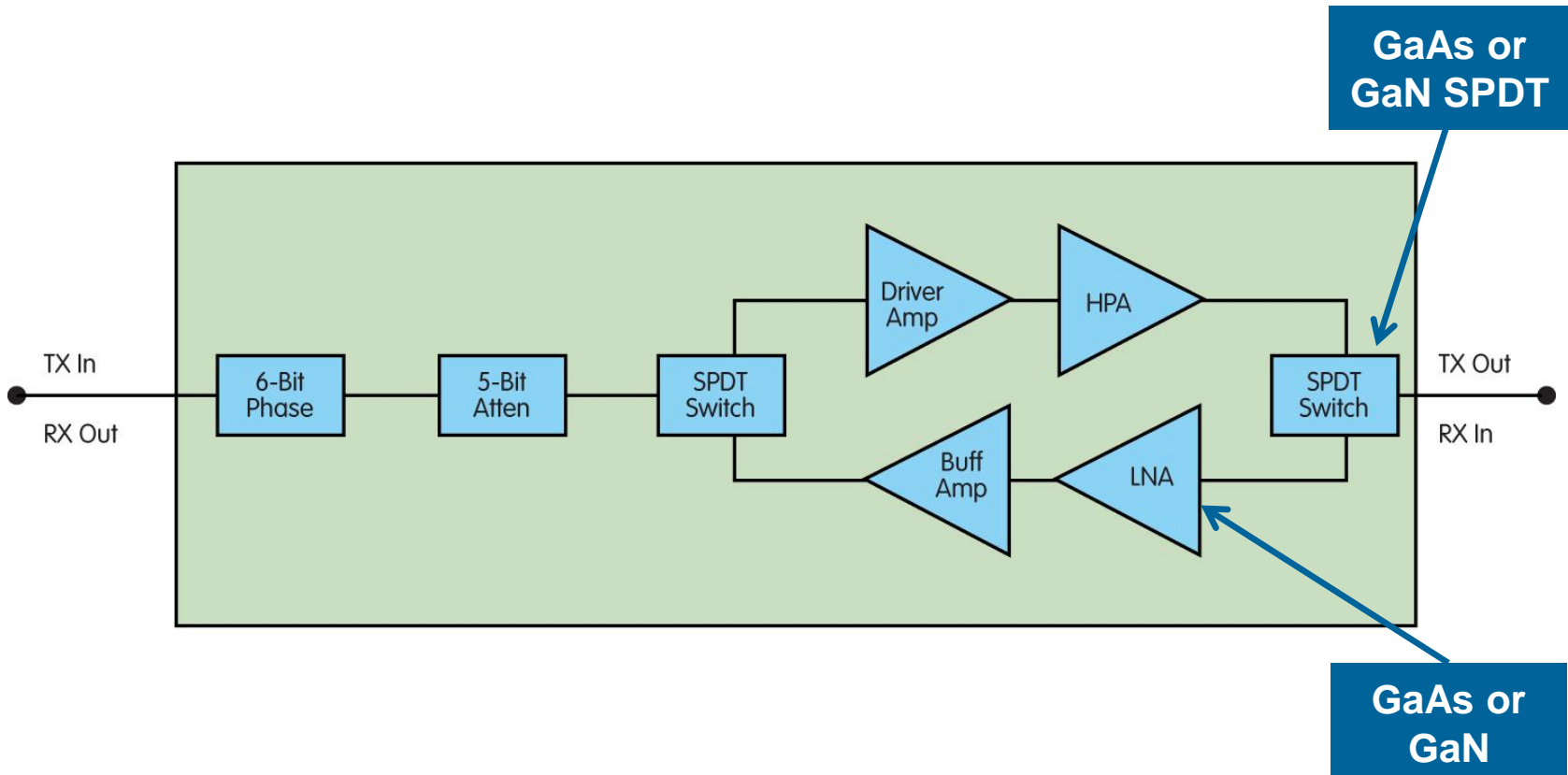
Low noise figure with high input RF power survivability.  
Do you still need a limiter?



# *Tx / Rx Module on a Single MMIC*

# Transmit Receive Functions on a Single MMIC

- Transmit, receive and control functions on a single MMIC delivers SWaP advantages

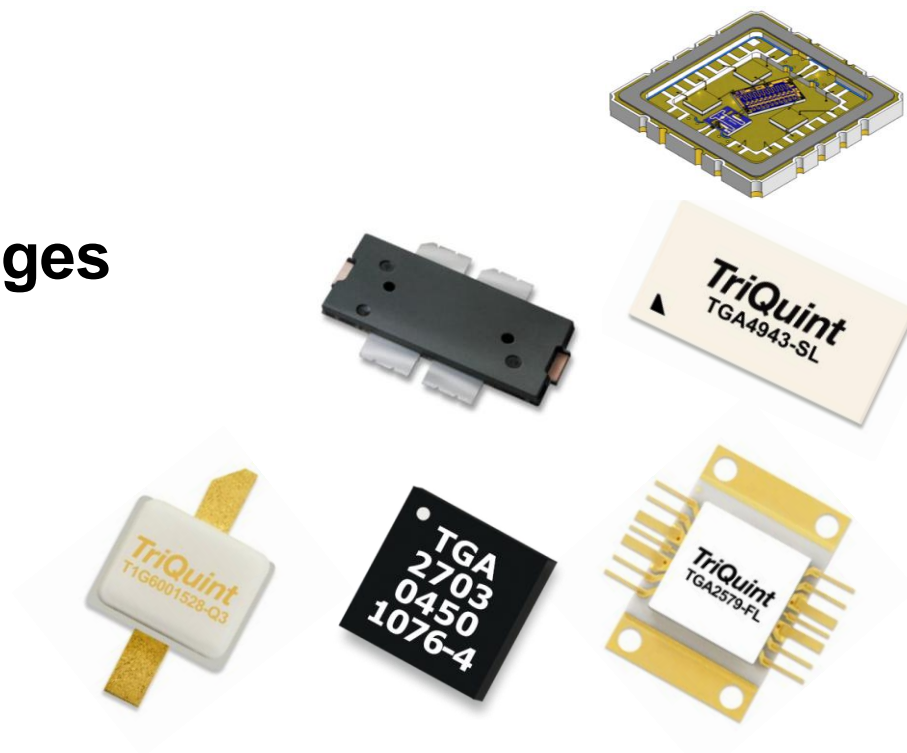




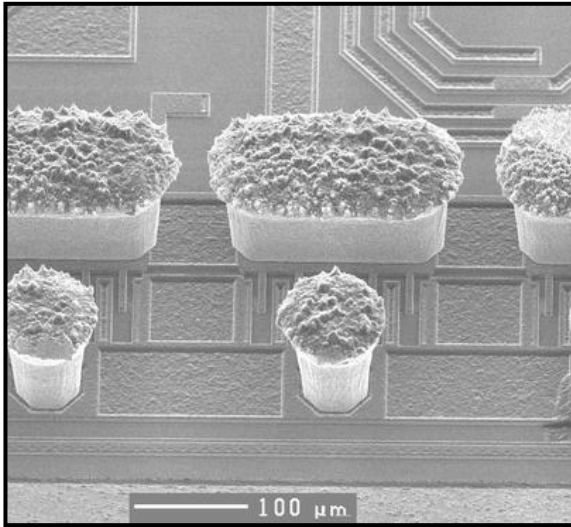
# *RF Packaging*

# RF Package Types

- **TriQuint's Cu-Flip™ process**
- **Surface mount packages**
  - Air cavity QFN
    - Ceramic or LCP
  - Over-molded QFN
  - Rogers laminate
- **High-power flange packages**
  - Cu-Moly based
  - Plastic over-molded

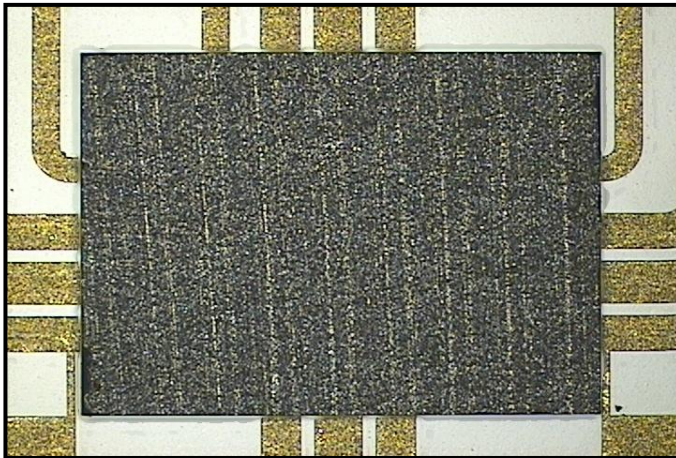


# CuFlip™ TriQuint's Cu-Bump Interconnect Technology



## ■ CuFlip™ advantages

- Low inductance connection
- Reduces performance variability
- Potential board and die size reduction

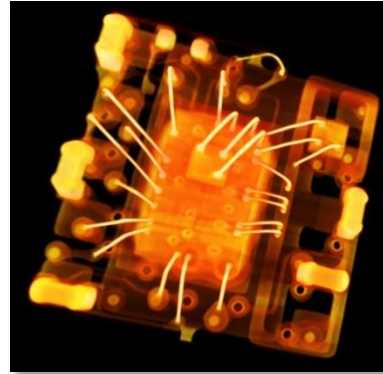


# Technology Advantage: BiHEMT and CuFlip™

## BiHEMT

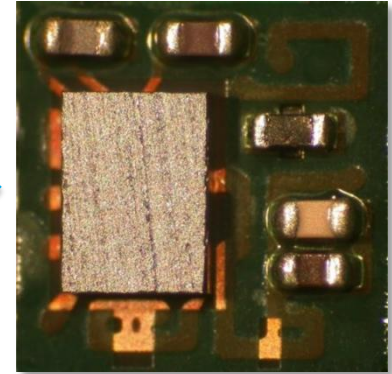
- Smaller, less complicated die
- Lower cost solution
- Provides path for higher integration

Conventional



VS

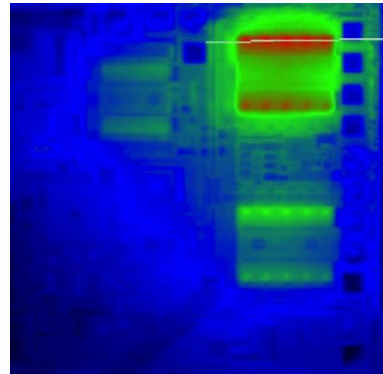
BiHEMT + CuFlip™



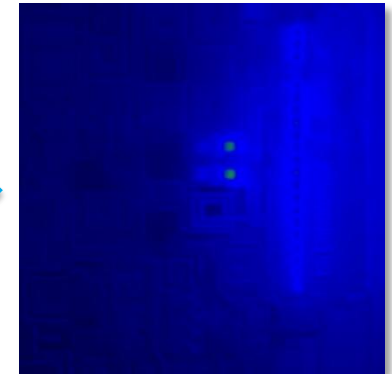
Size reduction and performance increase with using enhanced process technology

## Cu-Flip™

- More efficient PA
- Cooler operation due to lower thermal impedance (30-50%)
- Less manufacturing variation



VS





# Summary

- **Power amplifier advancements result in SWaP improvements for both center feed and AESA radar**
- **GaN RF switches and high-survivability LNAs improve performance and decrease size of the overall radar**
- **Packaging drives lower cost unit price and low cost assembly**

# *Thank You!*

## **Dean White**

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